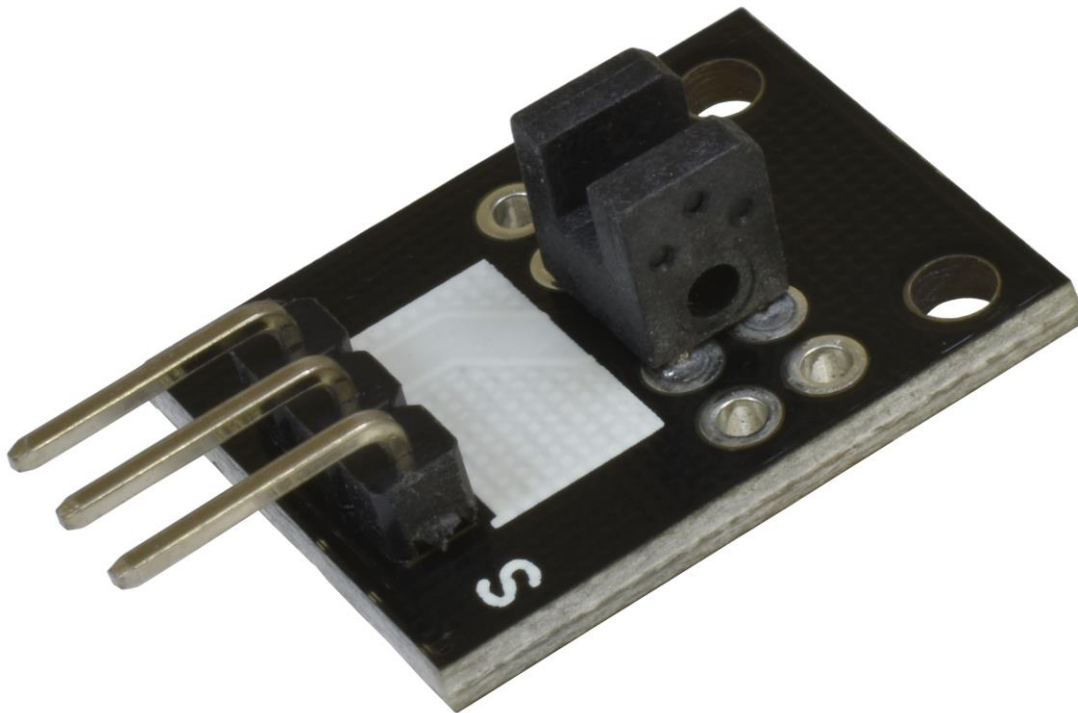
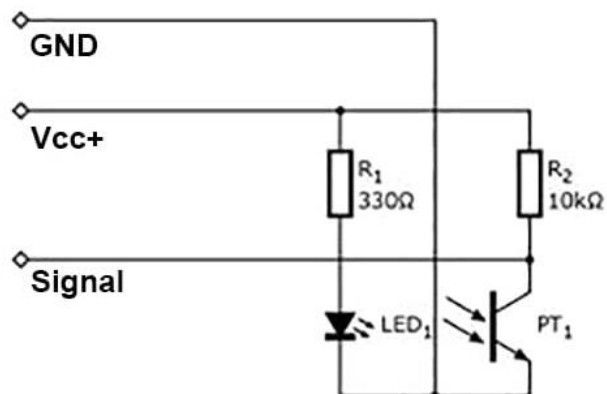


LIGHT SLOTTED OPTO COUPLER MODULE - HR0037



Specifications	
Function	Slotted Opto Coupler
Model	KY-010
Chip type	EE-SX1103
Operating Voltage	3.3 to 5V
Dimensions	19 x 15 mm

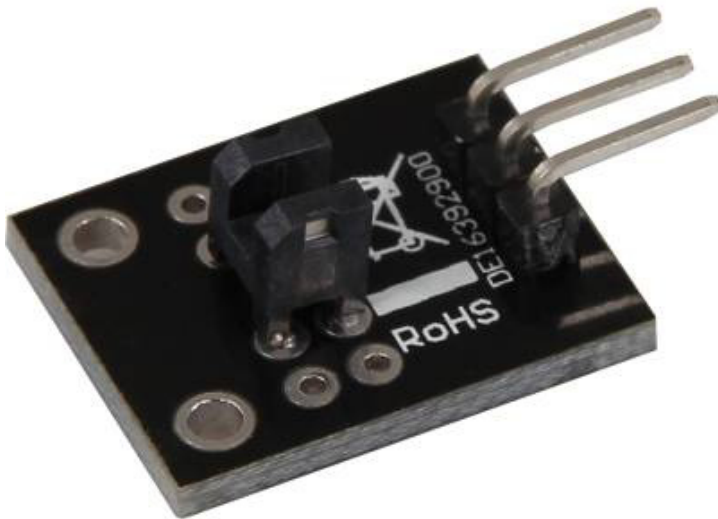


KY-010 Light barrier-module

Contents

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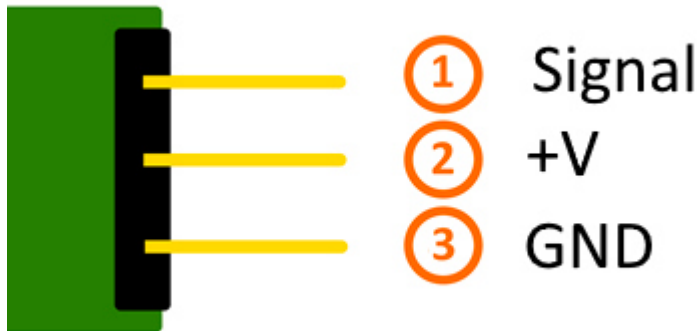
Picture



Technical data / Short description

The connection between both input pins will be interrupted if the optical barrier is being interrupted.

Pinout



Code example Arduino

In this program, a LED will flash up, if a signal was detected at the sensor. You can also use the modules KY-011, KY-016 or KY-029 as LEDs.

```
int Led = 13 ;// Declaration of the LED-output pin
int Sensor = 10; // Declaration of the Sensor-input pin
int val; // Temporary variable

void setup ()
{
  pinMode (Led, OUTPUT) ; // Initialization output pin
  pinMode (Sensor, INPUT) ; // Initialization sensorpin
}

void loop ()
{
  val = digitalRead (Sensor) ; // The current signal at the sensor will be read.

  if (val == HIGH) //The led will flash up, if a signal was detected.
  {
    digitalWrite (Led, HIGH);
  }
  else
  {
    digitalWrite (Led, LOW);
  }
}
```

Connections Arduino:

LED +	= [Pin 13]
LED -	= [Pin GND]
Sensor Signal	= [Pin 10]
Sensor +V	= [Pin 5V]
Sensor -	= [Pin GND]

Example program download[SensorTest_Arduino_inverted](#)**Code example Raspberry Pi**

```
# Needed modules will be imported and configured
import RPi.GPIO as GPIO
import time

GPIO.setmode(GPIO.BCM)

# The input pin which is connected with the sensor.
GPIO_PIN = 24
GPIO.setup(GPIO_PIN, GPIO.IN, pull_up_down = GPIO.PUD_DOWN)

print "Sensor-Test [press ctrl+c to end the test]"

# This outputFunction will be started at signal detection
def outputFunction(null):
    print("Signal detected")

# The outputFunction will be started at the moment of a signal detection (raising edge).
GPIO.add_event_detect(GPIO_PIN, GPIO.RISING, callback=outputFunction, bouncetime=100)

# Main program loop
try:
    while True:
        time.sleep(1)

# Scavenging work after the end of the program
except KeyboardInterrupt:
    GPIO.cleanup()
```

Connections Raspberry Pi:

Signal	=	GPIO24	[Pin 18]
+V	=	3,3V	[Pin 1]
GND	=	GND	[Pin 6]

Example program download[SensorTest_RPi_inverted](#)

To start, enter the command:

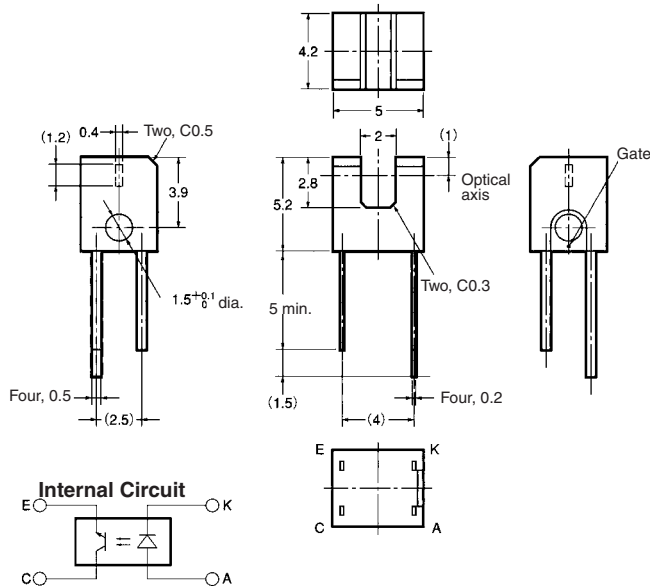
```
sudo python SensorTest_RPi_inverted.py
```

Photomicrosensor (Transmissive) EE-SX1103

⚠ Be sure to read *Precautions* on page 25.

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



Terminal No.	Name
A	Anode
K	Cathode
C	Collector
E	Emitter

Unless otherwise specified, the tolerances are ± 0.2 mm.

■ Features

- Ultra-compact with a sensor width of 5 mm and a slot width of 2 mm.
- PCB mounting type.
- High resolution with a 0.4-mm-wide aperture.

■ Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rated value
Emitter	Forward current	I_F 50 mA (see note 1)
	Pulse forward current	I_{FP} ---
	Reverse voltage	V_R 5 V
Detector	Collector–Emitter voltage	V_{CEO} 30 V
	Emitter–Collector voltage	V_{ECO} 4.5 V
	Collector current	I_C 30 mA
	Collector dissipation	P_C 80 mW (see note 1)
Ambient temperature	Operating	T_{opr} -25°C to 85°C
	Storage	T_{stg} -30°C to 100°C
Soldering temperature	T_{sol}	260°C (see note 2)

Note: 1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C .

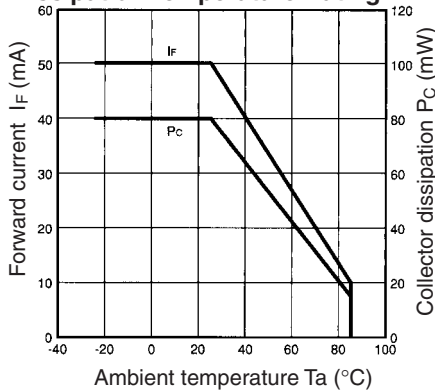
2. Complete soldering within 3 seconds.

■ Electrical and Optical Characteristics (Ta = 25°C)

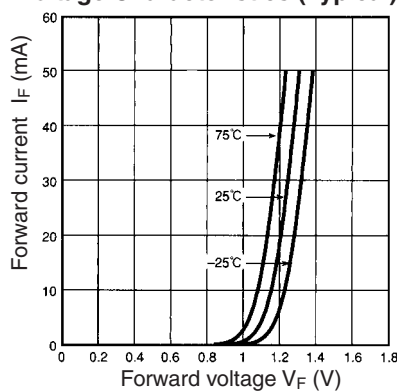
Item	Symbol	Value	Condition
Emitter	Forward voltage	V_F 1.3 V typ., 1.6 V max.	$I_F = 50$ mA
	Reverse current	I_R 10 μA max.	$V_R = 5$ V
	Peak emission wavelength	λ_P 950 nm typ.	$I_F = 50$ mA
Detector	Light current	I_L 0.5 mA min.	$I_F = 20$ mA, $V_{CE} = 5$ V
	Dark current	I_D 500 nA max.	$V_{CE} = 10$ V, 0 lx
	Leakage current	I_{LEAK} ---	---
	Collector–Emitter saturated voltage	$V_{CE}(\text{sat})$ 0.4 V max.	$I_F = 20$ mA, $I_L = 0.3$ mA
	Peak spectral sensitivity wavelength	λ_P 800 nm typ.	$V_{CE} = 5$ V
Rising time	t_r	10 μs typ.	$V_{CC} = 5$ V, $R_L = 100$ Ω , $I_F = 20$ mA
Falling time	t_f	10 μs typ.	$V_{CC} = 5$ V, $R_L = 100$ Ω , $I_F = 20$ mA

Engineering Data

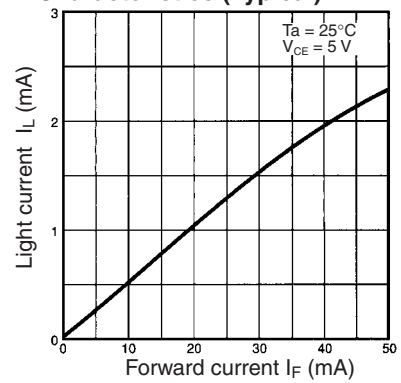
Forward Current vs. Collector Dissipation Temperature Rating



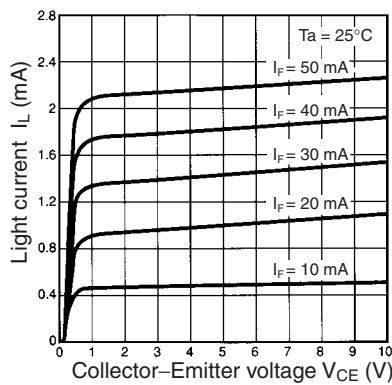
Forward Current vs. Forward Voltage Characteristics (Typical)



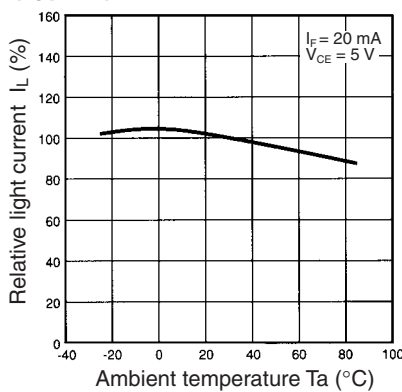
Light Current vs. Forward Current Characteristics (Typical)



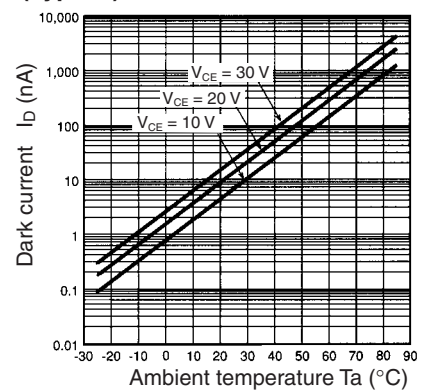
Light Current vs. Collector-Emitter Voltage Characteristics (Typical)



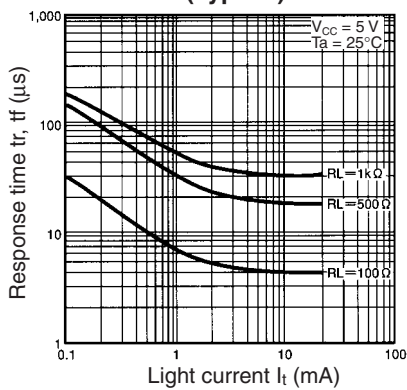
Relative Light Current vs. Ambient Temperature Characteristics (Typical)



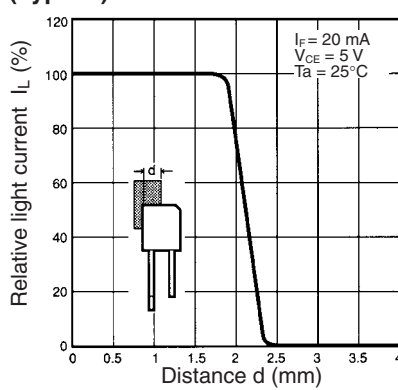
Dark Current vs. Ambient Temperature Characteristics (Typical)



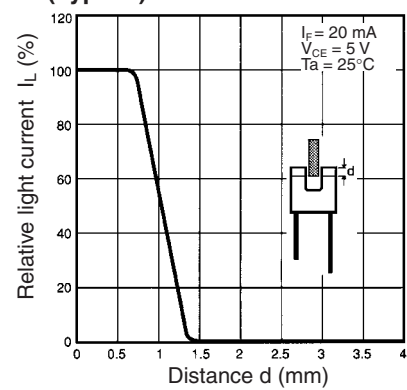
Response Time vs. Light Current Characteristics (Typical)



Sensing Position Characteristics (Typical)



Sensing Position Characteristics (Typical)



Response Time Measurement Circuit

